COMPLIANT



Low-Voltage, Low R_{ON}, Single Analog Switch In miniQFN-6 Package

DESCRIPTION

The DG2511, DG2512, DG2513 are low on-resistance, single-pole/double-throw or single-pole/single-throw monolithic CMOS analog switch. It is designed for low voltage applications. The DG2511, DG2512, DG2513 are ideal for portable and battery powered equipment, requiring high performance and efficient use of board space. In additional to the low on-resistance (1.3 Ω at 2.7 V).

The DG2511 is an SPDT and the DG2512, DG2513 are SPST. The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG2511, DG2512, DG2513 are built on Vishay Siliconix's low voltage JI5L process. An epitaxial layer prevents latchup.

Break-before-make is guaranteed.

The DG2511, DG2512, DG2513 represents a breakthrough in packaging development for analog switching products. The miniQFN-6 package (1.2 x 1 mm).

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with NiPdAu device terminations, the lead (Pb)-free "-E4" suffix is being used as a designator.

FEATURES

- Low voltage operation (1.8 V to 5.5 V)
- Low on-resistance R_{ON} : 1.3 Ω at 2.7 V
- Low charge injection
- Latch-up current > 300 mA (JESD78A)
- miniQFN-6 package (1.2 x 1 mm)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

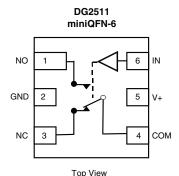
BENEFITS

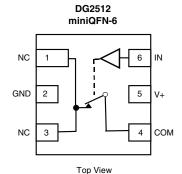
- Reduced power consumption
- Simple logic interface
- High accuracy
- Reduce board space
- Guaranteed 2 V operation

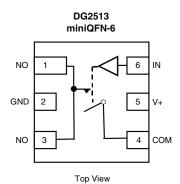
APPLICATIONS

- Cellular phones
- Communication systems
- Portable test equipment
- Battery operated systems
- Sample and hold circuits
- ADC and DAC applications
- Low voltage data acquisition systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION







Ax

Device Marking: Ax for DG2511 Bx for DG2512 Cx for DG2513 x = Date/Lot Traceability Code Note: Pin 1 has long lead

TRUTH TABLE						
Logic	NC	NO				
0	On	Off				
1	Off	On				

COMMERCIAL ORDERING INFORMATION						
Package	Part Number					
miniQFN-6	DG2511DN-T1-E4					
with Tape and Reel	DG2512DN-T1-E4 DG2513DN-T1-E4					
	Package miniQFN-6 Lead (Pb)-free					

DG2511, DG2512, DG2513

Vishay Siliconix



ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Reference V+ to GND		- 0.3 to + 6	V			
IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3)				
Continuous Current (NO, NC, COM pins)		± 150	mA			
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 300	IIIA			
Storage Temperature	ge Temperature D Suffix		°C			
Power Dissipation (Packages) ^b	miniQFN-6 ^c	160	mW			

Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 2 mW/°C above 70 °C.

SPECIFICATIONS (V+	= 3 V)						
		Test Conditions		Limits - 40 °C to 85 °C		- 00	
_		Otherwise Unless Specified					
Parameter	Symbol	V+ = 3 V, ± 10 %,V _{IN} = 0.4 V or 2 V ^e	Temp. ^a	Min.b	Typ. ^c	Max. ^b	Unit
Analog Switch			1	T		,	
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	٧
On-Resistance	R _{ON}	V+ = 2.7 V, V _{COM} = 0.5 V/1.5 V	Room Full		1.4	1.7 1.9	Ω
R _{ON} Match	ΔR_{ON}	I_{NO} , $I_{NC} = 100 \text{ mA}$	Room			0.15	
R _{ON} Flatness	R _{ON} Flatness	INO, INC = 100 IIIA	Room		0.3	0.4	
Outlet Off Leaders Outlet	I _{NO(off)}	V+ = 3.3 V,	Room Full	- 2 - 20		2 20	
Switch Off Leakage Current ^f	I _{COM(off)}	V_{NO} , V_{NC} = 1 V/3 V, V_{COM} = 3 V/1 V	Room Full	- 2 - 20		2 20	nA
Channel-On Leakage Current ^f	I _{COM(on)}	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 1 \text{ V/3 V}$	Room Full	- 2 - 20		2 20	
Digital Control							
Input High Voltage	V _{INH}		Full	1.6			V
Input Low Voltage	V _{INL}		Full			0.4	ľ
Input Capacitance	C _{in}		Full		4		pF
Input Current	I _{INL} or I _{INH}	$V_{IN} = 0$ or $V+$	Full	1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t _{ON}	$V+ = 2.7 \text{ V}, V_{NO} \text{ or } V_{NC} = 1.5 \text{ V},$	Room Full		18	43 49	
Turn-Off Time	t _{OFF}	$R_L = 50 \Omega$, $C_L = 35 pF$	Room Full		7	32 34	ns
Break-Before-Make Time	t _{BBM}		Room	1	12		
Charge Injection ^d	Q _{INJ}	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega$	Room		3		рC
Off-Isolation ^d	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 1 MHz$	Room		- 58		٩D
Crosstalk ^d	X _{TALK}	11 <u>1</u> = 30 32, O <u>L</u> = 3 pr, r = 1 ΜΠΖ	Room		- 64		dB
N _O , N _C Off Capacitance ^d	C _{NO(off)} C _{NC(off)}	V _{IN} = 0 or V+, f = 1 MHz	Room		21		pF
Channel-On Capacitance ^d	C _{ON}		Room		61		
Power Supply			1		1		ı
Power Supply Range	V+			1.8		5.5	V
Power Supply Current	I+	$V_{IN} = 0 \text{ or } V+$			0.01	1	μΑ



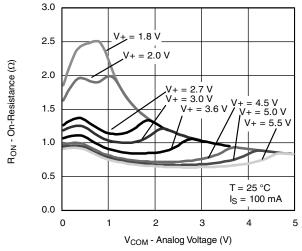
SPECIFICATIONS (V+	= 5 V)						
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 5 V$, $\pm 10 \%$, $V_{IN} = 0.6 V$ or $1.8 V^e$	Temp.a	Min.b	Typ.c	Max.b	Unit
Analog Switch			•				
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V
On-Resistance	R _{ON}	V. 45 V.V. 05 V/05 V	Room Full		1	1.3 1.45	
R _{ON} Match	ΔR_{ON}	$V+ = 4.5 \text{ V}, V_{COM} = 0.5 \text{ V}/2.5 \text{ V},$ $I_{NO}, I_{NC} = 100 \text{ mA}$	Room			0.15	Ω
R _{ON} Flatness	R _{ON} Flatness	I _{NO} , I _{NC} = 100 IIIA	Room		0.3	0.4	
Switch Off Leakage Current	I _{NO(off)} I _{NC(off)}	V+ = 5.5 V,	Room Full	- 2 - 20		2 20	
Owner on Leakage ourient	I _{COM(off)}	V_{NO} , V_{NC} = 1 V/4.5 V, V_{COM} = 4.5 V/1 V	Room Full	- 2 - 20		2 20	nA
Channel-On Leakage Current	I _{COM(on)}	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 1 \text{ V}/4.5 \text{ V}$	Room Full	- 2 - 20		2 20	
Digital Control							
Input High Voltage	V _{INH}		Full	1.8			V
Input Low Voltage	V _{INL}		Full			0.6	V
Input Capacitance	C _{in}		Full		4		pF
Input Current	I _{INL} or I _{INH}	$V_{IN} = 0 \text{ or } V+$	Full	1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t _{ON}		Room Full		11	35 39	
Turn-Off Time	t _{OFF}	V_{NO} or V_{NC} = 2.5 V, R_L = 50 Ω , C_L = 35 pF	Room Full		6	31 33	ns
Break-Before-Make Time	t _{BBM}		Room	1	5		
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		14		рC
Off-Isolation ^d	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 1 MHz$	Room		- 58		40
Crosstalk ^d	X _{TALK}	$\Pi_{L} = 30.32$, $\Theta_{L} = 3 \text{ pr}$, $\Gamma = 1 \text{ N/HZ}$	Room		- 64		dB
N _O , N _C Off Capacitance ^d	C _{NO(off)} C _{NC(off)}	V _{IN} = 0 or V+, f = 1 MHz	Room		19		pF
Channel-On Capacitance ^d	C _{ON}		Room		61		-
Power Supply							
Power Supply Range	V+	V _{IN} = 0 or V+		1.8		5.5	V
Power Supply Current	l+	V _{IN} = 0 01 V+			0.01	1	μΑ

Notes:

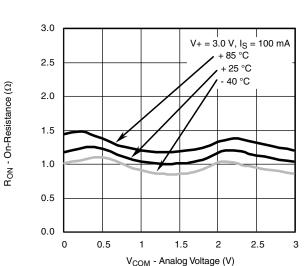
- a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

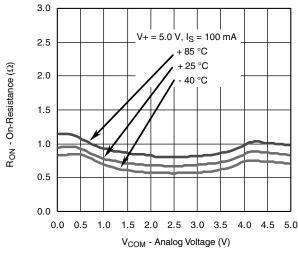
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



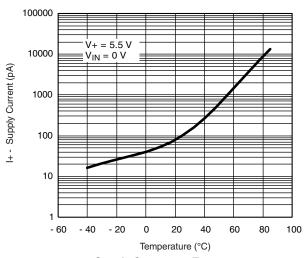
R_{ON} vs. V_{COM} and Supply Voltage



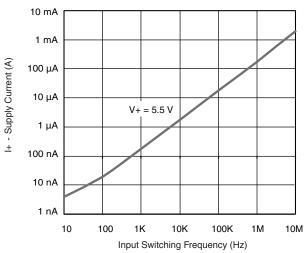
R_{ON} vs. Analog Voltage and Temperature



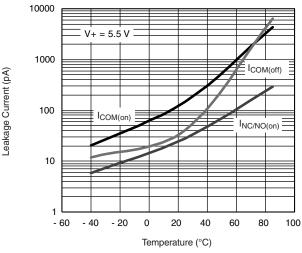
R_{ON} vs. Analog Voltage and Temperature



Supply Current vs. Temperature



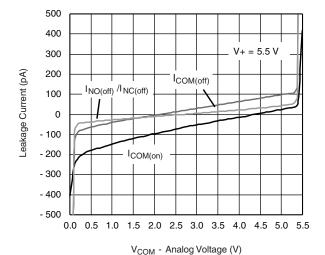
Supply Current vs. Input Switching Frequency



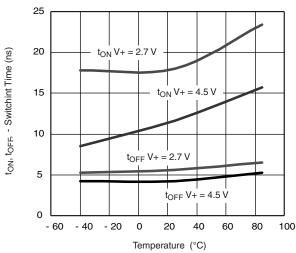
Leakage Current vs. Temperature



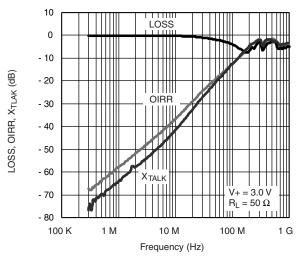
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



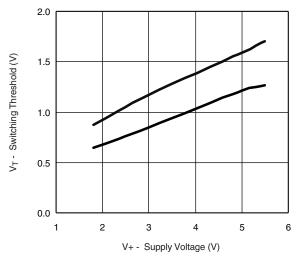
Leakage vs. Analog Voltage



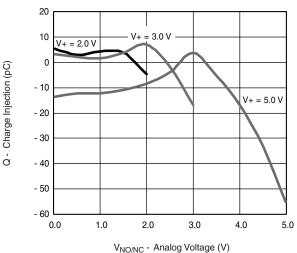
Switching Time vs. Temperature and Supply Voltage



Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



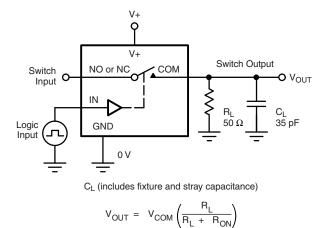
Switching Threshold vs. Supply Voltage

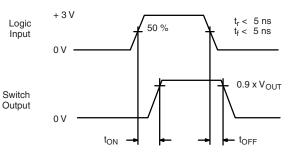


Charge Injection vs. Analog Voltage

TEST CIRCUITS







Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

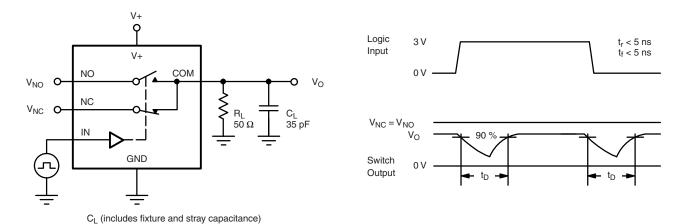


Figure 2. Break-Before-Make Interval

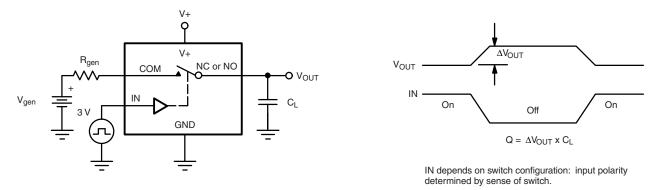


Figure 3. Charge Injection



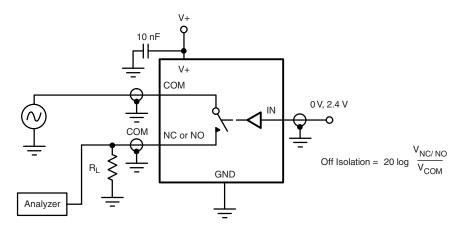


Figure 4. Off-Isolation

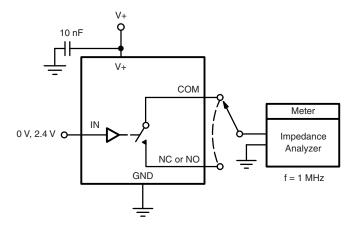
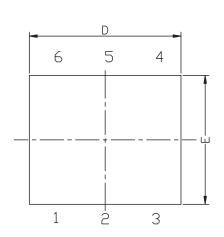


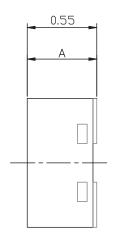
Figure 5. Channel Off/On Capacitance

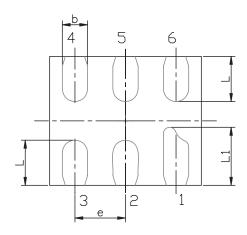
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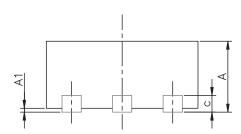


MINI QFN-6L CASE OUTLINE







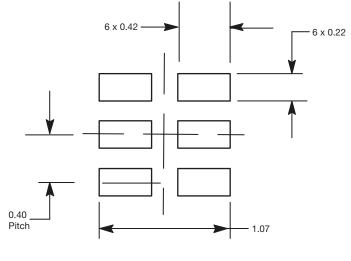


DIM	MILLIMETERS			INCHES			
Dilvi	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.	
Α	0.50	0.55	0.60	0.0197	0.0217	0.0236	
A1	0.00	-	0.05	0.000	0.002		
b	0.15	0.20	0.25	0.006	0.008	0.010	
С	0.15 REF				0.006 REF		
D	1.15	1.20	1.25	0.045	0.049		
E	0.95	1.00	1.05	0.037	0.039	0.041	
е	0.40 BSC				0.016 BSC		
L	0.30	0.35	0.40	0.012	0.014	0.016	
L1	0.40	0.45	0.50	0.016	0.018	0.020	

ECN T-07039-Rev. A, 12-Feb-07 DWG: 5958



RECOMMENDED MINIMUM PADS FOR MINI QFN 6L



Mounting Footprint Dimensions in mm



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